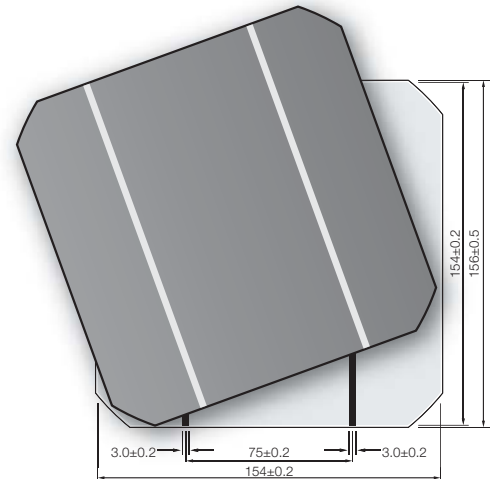
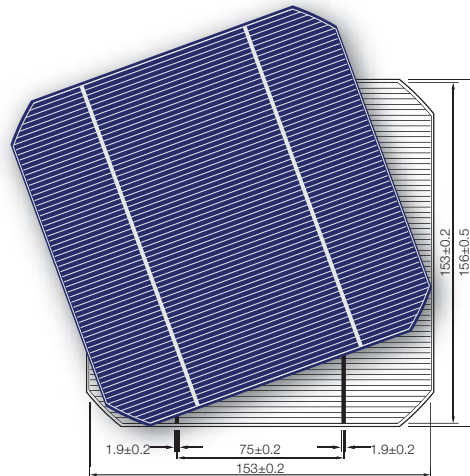


# 156S

## Mono 6" (R200)

156SOR2 (2 bus-bars)

Monocrystalline silicon solar cells



### MECHANICAL DATA AND DESIGN

**Format** 156mm×156mm±0.5mm

**Thickness** 190µm±20µm

**Front(-)** 1.9mm bus bars(silver), blue anti-reflecting coating(silicon nitride)

**Back(+)** 3mm wide soldering pads(silver) back surface field(aluminium)

### TEMPERATURE COEFFICIENTS

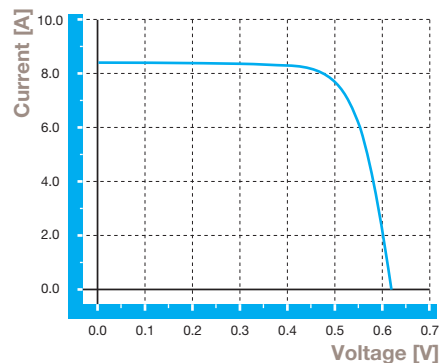
**TkVoltage** -0.346%/K

**TkCurrent** +0.036%/K

**TkPower** -0.47%/K

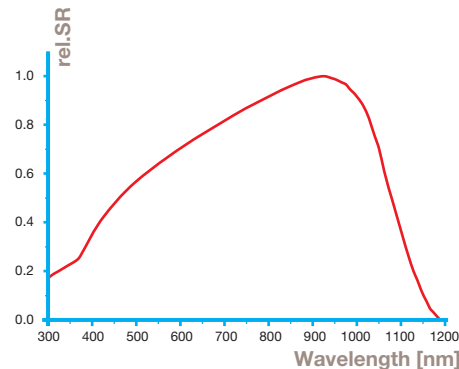
	Efficiency(%)	Pmpp(W)	Ump(V)	Imp(A)	Uoc(V)	Isc(A)	FF(%)
Format	17.75-18.00	4.27	0.527	8.102	0.628	8.615	78.90
Thickness	17.50-17.75	4.21	0.521	8.083	0.627	8.584	78.23
Front(-)	17.25-17.50	4.15	0.517	8.028	0.626	8.550	77.57
	17.00-17.25	4.09	0.513	7.982	0.624	8.495	77.23
Back(+)	16.75-17.00	4.03	0.512	7.873	0.622	8.408	77.15
	16.50-16.75	3.97	0.505	7.871	0.621	8.390	76.14
TkVoltage	16.25-16.50	3.91	0.502	7.796	0.620	8.372	75.45
	16.00-16.25	3.85	0.499	7.714	0.620	8.350	75.09
TkCurrent	15.75-16.00	3.79	0.498	7.601	0.620	8.125	75.34
	15.50-15.75	3.73	0.498	7.480	0.619	8.005	75.34

### IV CURVE



\*calibrated against fraunhofer ISE freiburg

### SPECTRAL RESPONSE



### INTENSITY DEPENDENCE

Intensity [W/m <sup>2</sup> ]	Isc* [mA]	Voc* [mV]
1000	1.0	1.000
900	0.9	0.995
500	0.5	0.966
300	0.3	0.940
200	0.2	0.919

\*Ratio of Voc(Isc) at reduced intensity to Voc(Isc) at 1000 W/m<sup>2</sup>